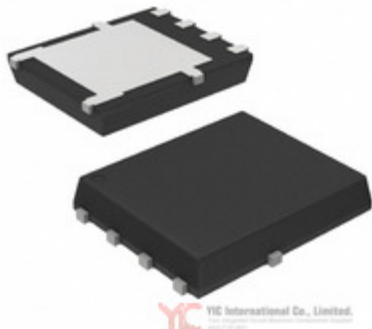

	<p>NVMFS5832NLWFT1G</p>
	<p>Hersteller-Teilenummer: NVMFS5832NLWFT1G</p>
	<p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p>
	<p>Teil der Beschreibung: MOSFET N-CH 40V 120A SO8FL</p>
<p>Image may be representation. See specs for product details.</p>	<p>Datenblätter:  NVMFS5832NLWFT1G.pdf</p>
	<p>RoHs Status: Bleifrei / RoHS-konform</p>
	<p>Lagerzustand: New original, 2000 pcs Stock Available.</p>
	<p>Liefern von: Hong Kong</p>
	<p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>

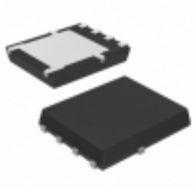
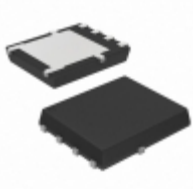
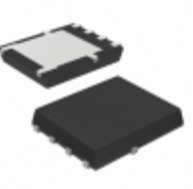
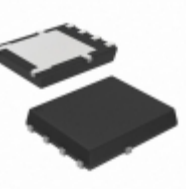
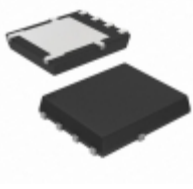
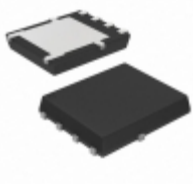
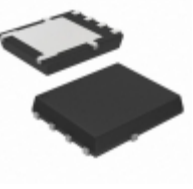
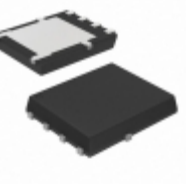
Spezifikationen

Teilenummer	NVMFS5832NLWFT1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 40V 120A SO8FL
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	2000 pcs Stock
VGS (th) (Max) @ Id	2.4V @ 250µA
Technologie	MOSFET (Metal Oxide)
Supplier Device-Gehäuse	5-DFN (5x6) (8-SOFL)
Serie	-
Rds On (Max) @ Id, Vgs	4.2 mOhm @ 20A, 10V
Verlustleistung (max)	3.7W (Ta), 127W (Tc)
Verpackung	Tape & Reel (TR)
Verpackung / Gehäuse	8-PowerTDFN
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Eingabekapazität (Ciss) (Max) @ Vds	2700pF @ 25V
Gate Charge (Qg) (Max) @ Vgs	51nC @ 10V
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	40V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	21A (Ta)

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RFQ NVMFS5832NLWFT1G E-Mail: Info@Y-IC.com

Sie können auch interessiert

<p>sein:</p>  <p>NVMFS5832NLWFT3G ON Semiconductor MOSFET N-CH 40V 120A SO8FL</p>	 <p>NVMFS5830NLWFT1G ON Semiconductor MOSFET N-CH 40V 172A SO8FL</p>	 <p>NVMFS5833NWFT3G ON Semiconductor MOSFET N-CH 40V SO8FL</p>	 <p>NVMFS5832NLT1G ON Semiconductor MOSFET N-CH 40V 120A SO8FL</p>
 <p>NVMFS5830NLWFT3G ON Semiconductor MOSFET N-CH 40V 172A SO8FL</p>	 <p>NVMFS5830NLT3G ON Semiconductor MOSFET N-CH 40V 185A SO8FL</p>	 <p>NVMFS5833NT3G ON Semiconductor MOSFET N-CH 40V SO8FL</p>	 <p>NVMFS5833NT1G ON Semiconductor MOSFET N-CH 40V SO8FL</p>

Verwandtes Hot-Keyword

Mehr

NVMFS5832NLWFT1G AMI Semiconductor / ON Semiconductor	NVMFS5832NLWFT1G Datenblatt	NVMFS5832NLWFT1G-Datenblätter	NVMFS5832NLWFT1G PDF	AMI Semiconductor / ON Semiconductor NVMFS5832NLWFT1G
NVMFS5832NLWFT1G Electronic	NVMFS5832NLWFT1G-Komponenten	NVMFS5832NLWFT1G-Verteiler	NVMFS5832NLWFT1G-Bild	NVMFS5832NLWFT1G-Teil
NVMFS5832NLWFT1G Preis	NVMFS5832NLWFT1G Hersteller	NVMFS5832NLWFT1G Bild	NVMFS5832NLWFT1G Aktie	NVMFS5832NLWFT1G Inventar
NVMFS5832NLWFT1G Neu	NVMFS5832NLWFT1G Original	NVMFS5832NLWFT1G garantiert	NVMFS5832NLWFT1G RFQ	NVMFS5832NLWFT1G Online bestellen

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HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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